

# RoHS



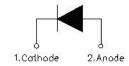
## **SBRF2045 SCHOTTKY RECTIFIER**



#### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=105°C, rectangular wave form	20	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>C</sub> = 25 °C	252	Α

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 20A, Pulse, T <sub>C</sub> = 25 °C	0.51	0.65	V
	$V_{F2}$	@ 20A, Pulse, T <sub>C</sub> = 125 °C	0.45	0.60	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_C = 25 ^{\circ}\text{C}$	0.06	1	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R,} T_C = 125^{\circ}C$	15	50	mA
Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C, f <sub>SIG</sub> = 1MHz	500	900	pF
Repetitive peak reverse current	I <sub>RRM</sub>	tp = 2 µs square F= 1 kHz	-	1	Α
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, IAS = 2 A, L = 1mH	-	2	mJ
Typical Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 μs, duty cycle < 2%

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com
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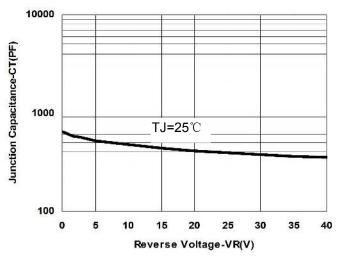




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> Jc	DC operation	1.5	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	ITO-220AC			

## **Ratings and Characteristics Curves**



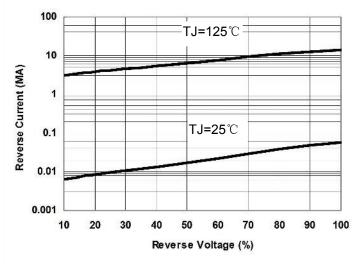


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

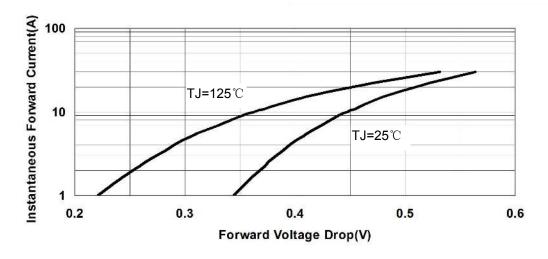


Fig.3-Typical Instantaneous Forward Voltage Characteristics

<sup>•</sup> China - Germany - Korea - Singapore - United States •

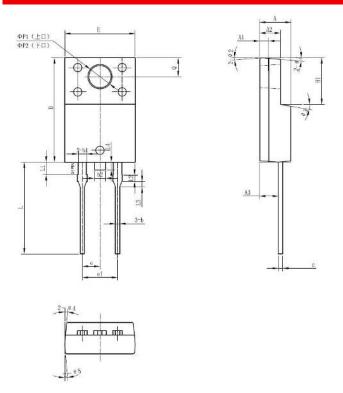
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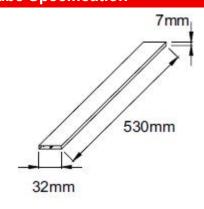


### **Mechanical Dimensions ITO-220AC**



SYMBOL	Millimeters			
STIVIBUL	MIN.	TYP.	MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	1.35	
b2	1.50	1.60	1.75	
С	0.55	0.60	0.75	
Q	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е	_	2.55	_	
e1	_	5.10	_	
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2	0.80	1.00	1.20	
L3	0.60	0.80	1.00	
L4	_	1.10	1.50	
<b>ФР1(</b> 上□)	3.30	3.50	3.70	
ΦP2(下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

## **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

 SBR
 = Device Type

 F
 = Package type

 20
 = Forward Current (20A)

 45
 = Reverse Voltage (45V)

 SSG
 = SSG

YY = Year WW = Week L = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
SBRF2045	ITO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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